Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L3	2502	((liquid near2 crystal) lcd) and substrate and ((pixel and reflect\$3) near2 electrode) and ((dielectric insulat\$4) near2 (film layer coat\$4))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/08 14:49
L4	78	((liquid near2 crystal) lcd) and substrate and (reflect\$4 near3 (film or plate or layer or coat\$4)) and (bump or dot or protru\$6 or recess or depress\$4)) and dielectric and (insulat\$4 near6 resin) and ((thin near3 film) or tft) and (scan\$4 or gate) and source and drain and (polarizer or (polariz\$6 near3 (plate or film or layer)) and (compensat\$4 or retard\$4) and ((pixel and reflect\$4) near2 electrode)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/08 14:56
L5	1803	349/113	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/08 14:56
L7	685	349/114	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/08 14:56
L8	268969	samsung.as. or lg.as.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/08 15:35
L9	2193	5 or 7	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/08 14:56
L10	152	9 and 8	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/08 14:57
L11	101	10 and (reflect\$4 near2 electrode)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/08 15:04

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L12	97	8 and passivation and (reflect\$4 near5 (bump\$5 uneven\$4 rough\$4 surface protru\$5)) and (pixel near2 electrode)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/08 15:36
L13	2	("6344888"   "6492700").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/12/08 15:13
L14	4	("4648691"   "4904060"   "5548425"   "5724111").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/12/08 15:20
L15	6	("20010022638"   "20020063824"   "20020093609"   "6512560"   "6532045"   "6620655").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/12/08 15:23
L16	4	("20010022634"   "20020118322"   "6157426"   "6501519").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/12/08 15:31
L17	7	("20020130324"   "5042916"   "5929489"   "6326641"   "6341002"   "6590226"   "6714267").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/12/08 15:34
L18	2690418	nec.as. fuji.as. hitachi.as. fujitsu.as. toshiba.as. "sharp.as"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/08 15:36
L20	104	18 and passivation and (reflect\$4 near5 (bump\$5 uneven\$4 rough\$4 surface protru\$5)) and (pixel near2 electrode)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/08 15:36
S1	1907	349/113	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/26 17:12
S2	457	349/114	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/26 17:13
S3	199	S1 and S2	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/26 17:13
S4	2165	S1 or S2	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/26 17:13

S5	6	S4 and substrate and ((reflect\$4 near3 (film or plate or layer or coat\$4)) and (bump or dot or protru\$6 or recess or depress\$4)) same (aluminum or silver)) and dielectric and (insulat\$4 near6 resin) and ((thin near3 film) or tft) and (scan\$4 or gate) and source and drain and (polarizer or (polariz\$6 near3 (plate or film or layer)) and (compensat\$4 or retard\$4) and transparent	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/26 18:43
S6	16	S4 and substrate and (reflect\$4 near3 (film or plate or layer or coat\$4)) and (bump or dot or protru\$6 or recess or depress\$4)) and dielectric and (insulat\$4 near6 resin) and ((thin near3 film) or tft) and (scan\$4 or gate) and source and drain and (polarizer or (polariz\$6 near3 (plate or film or layer)) and (compensat\$4 or retard\$4) and electrode	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/08 14:49
S7	14	S4 and substrate and (reflect\$4 near3 (film or plate or layer or coat\$4)) and (bump or dot or protru\$6 or recess or depress\$4)) and dielectric and (insulat\$4 near6 resin) and ((thin near3 film) or tft) and (scan\$4 or gate) and source and drain and (polarizer or (polariz\$6 near3 (plate or film or layer)) and (compensat\$4 or retard\$4) and electrode and (color near3 filter)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/26 17:36
S8	9	S1 and substrate and (reflect\$4 near3 (film or plate or layer or coat\$4)) and (bump or dot or protru\$6 or recess or depress\$4)) and dielectric and (insulat\$4 near6 resin) and ((thin near3 film) or tft) and (scan\$4 or gate) and source and drain and (polarizer or (polariz\$6 near3 (plate or film or layer)) and (compensat\$4 or retard\$4) and electrode and (color near3 filter)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/26 19:05
59	41	S1 and substrate and ((reflect\$4 near3 (film or plate or layer or coat\$4)) and (bump or dot or protru\$6 or recess or depress\$4)) and dielectric and (insulat\$4 near6 resin) and ((thin near3 film) or tft) and ((tranaparent or pixel) near3 electrode) and (color near3 filter)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/26 19:05

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510	1	S1 and substrate and (dielectric near8 (color near3 filter)) and (insulat\$4 near6 resin) and ((thin near3 film) or tft) and ((tranaparent or pixel) near3 electrode)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/26 17:52
S11	54	S1 and substrate and ((reflect\$4 near3 (film or plate or layer or coat\$4)) and (bump or dot or protru\$6 or recess or depress\$4)) and (dielectric or passivation) and (insulat\$4 near6 resin) and ((thin near3 film) or tft) and ((tranaparent or pixel) near3 electrode) and (color near3 filter)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/26 18:57
S12	0	"349"/\$6 and substrate and ((reflect\$4 near3 (film or plate or layer or coat\$4)) and (bump or dot or protru\$6 or recess or depress\$4)) same (aluminum or silver)) and passivation and (insulat\$4 near6 resin) and ((thin near3 film) or tft) and (scan\$4 or gate) and source and drain and (polarizer or (polariz\$6 near3 (plate or film or layer)) and (compensat\$4 or retard\$4) and transparent	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/26 18:43
S13	140	"349"/\$6 and substrate and ((reflect\$4 near3 (film or plate or layer or coat\$4)) and (bump or dot or protru\$6 or recess or depress\$4)) and (dielectric or passivation) and (insulat\$4 near6 resin) and ((thin near3 film) or tft) and ((tranaparent or pixel) near3 electrode) and (color near3 filter)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/26 18:57
S14	2243	349/106	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/26 19:05
S15	163	"16" and substrate and ((reflect\$4 near3 (film or plate or layer or coat\$4)) and (bump or dot or protru\$6 or recess or depress\$4)) and dielectric and (insulat\$4 near6 resin) and ((thin near3 film) or tft) and ((tranaparent or pixel) near3 electrode) and (color near3 filter)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/26 19:05
S16	10373	lg.as. and park.in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/26 19:33

S17	12	S16 and S14	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/26 19:26
S18	7	S16 and S1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/26 19:26
S19	151	S16 and (color\$2 near3 (filter or layer))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/26 19:40
S20	11	S19 and S14	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/26 19:40
S21	22851	lg.as. and kim.in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/26 19:40
S22	406	S21 and (color\$2 near3 (filter or layer))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/26 19:40
S23	21	S22 and S1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/26 19:40